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Tunable Color of $\text{Ce}^{3+}/\text{Th}^{3+}/\text{Mn}^{2+}$ -Coactivated CaScAlSiO₆ via Energy Transfer: A Single-Component Red/White-Emitting Phosphor

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ABSTRACT: A series of single-component red/white-emitting $CaScAlSiO₆:Ce³⁺, Tb³⁺, Mn²⁺ phosphors have been$ synthesized by a solid-state reaction. It is observed that $CaScAlSiO₆:Ce³⁺, Tb³⁺$ phosphors exhibit two dominating bands situated at 380 and 542 nm, originating from the allowed 5d \rightarrow 4f transition of the Ce³⁺ ion and the ⁵D₄ \rightarrow ⁷F_J $= (J = 6, 5, 4, 3)$ transition of the Tb³⁺ ion, respectively. As for CaScAlSiO₆:Ce³⁺,Mn²⁺, our results indicate that Mn²⁺ may occupy not only a Ca^{2+} site to generate an orange emission $[Mn^2+(I)]$ at 590 nm but also a Sc^{3+} site to generate a red emission $[Mn^{2+}(II)]$ at 670 nm. Both energy transfers from

 Ce^{3+} to Tb³⁺ and from Ce^{3+} to Mn²⁺ in the CaScAlSiO₆ host are investigated and have been demonstrated to be of the resonant type via a dipole–dipole mechanism. By proper tuning of the relative composition of Tb³⁺/Mn²⁺, white light can also be achieved upon excitation of UV light, indicating that the developed phosphor may potentially be used as a single-component red/whiteemitting phosphor for UV-light-emitting diodes.

1. INTRODUCTION

Phosphor-converted white-light-emitting diodes (LEDs) have gained enormous commercial interest because of their high luminous efficiency, long lifetimes, environmentally friendly features, etc.1−⁴ The most dominant way to create a white LED is by c[om](#page-5-0)bining a blue InGaN chip with $Y_3Al_5O_{12}$ $Y_3Al_5O_{12}$ $Y_3Al_5O_{12}$:Ce³⁺(YAG:Ce)-based yellow phosphors.^{5,[6](#page-5-0)} However, the device based on this phosphor exhibits a poor colorrendering index and a high correlated color temperature because of the lack of red light at long wavelength and limits expansion of the LED application.^{7−9} Current lighting technology employs UV LED chips wi[th](#page-5-0) [r](#page-5-0)ed, green, and blue phosphors to improve this problem. This approach provides white LEDs with excellent color-rendering indexes and can generate warm white light, but the luminescence efficiency is low in this system owing to the strong reabsorption of blue light by the red and green phosphors.^{10−12} Recently, many researchers have exploited and fabrica[ted](#page-5-0) [n](#page-5-0)ovel multicoloremitting phosphors into a UV/NUV chip, but disadvantages of poor luminous efficiency resulting from energy reabsorption in these cases also existed.^{13−16} In this regard, the search for a new single-component ph[ospho](#page-5-0)r pumped by UV chips is of significance for white LEDs to avoid the intrinsic color balance, device complication, and high-cost problems associated with using multicolor-emitting components.

In view of the luminescent species, the Ce^{3+} ion not only exhibits good performances for its special optical properties of broad band emission but also can act as an efficient sensitizer.

Recently, many researchers have studied the energy-transfer mechanism between Ce^{3+} and Tb^{3+} or Ce^{3+} and Mn^{2+} in a proper single host lattice for LED application, such as $Na_2Gd_2B_2O_7$: Ce^{3+} , Tb^{3+} , 17 $Ca_2Al_3O_6F$: Ce^{3+} , Tb^{3+} , 18 $Ca_3Sc_2Si_3O_{12}$ $Ca_3Sc_2Si_3O_{12}$ $Ca_3Sc_2Si_3O_{12}$: Ce^{3+} ,Mn²⁺,^{19,20} and YAG: Ce^{3+} ,Mn²⁺,Si^{4+ 21} [In](#page-5-0) these systems, the lumi[nesce](#page-5-0)nt efficiency of Tb^{3+} and Mn^{2+} Mn^{2+} Mn^{2+} singly doped phosphors is very low upon UV/blue-light excitation because of the 4f-4f weak absorption for Tb³⁺ and the forbidden ${}^4T_1 \rightarrow {}^6A_1$ transition for Mn^{2+} .^{22,23} However, by the introduction of an efficient sensitizer of Ce^{3+} Ce^{3+} , the energy would be transferred from the 5D level of Ce^{3+} to the ${}^5D_{3,4}$ level of Tb^{3+} or to the 4G level of Mn^{2+} , which helps Tb^{3+} and Mn^{2+} ions to emit efficiently. In particular, when Tb^{3+} and Mn^{2+} were both doped into the same host matrix, their emission colors can be easily tuned by varying the relative compositions of Tb^{3+}/Mn^{2+} . This advantage has been utilized to develop new tridoped phosphors, which were reported by many research groups.^{24−28}

In this research, we [report](#page-5-0) our recent investigation results on the luminescence and color tunability of a red/white-emitting $CaScAlSiO₆:Ce³⁺, Tb³⁺, Mn²⁺ phosphor. To the best of our$ knowledge, there has been no reported study on $Ce^{3+}/Tb^{3+}/$ Mn^{2+} activated or coactivated in the CaScAlSiO₆ host in the literature. By variation of the relative dopant concentrations of Tb^{3+} and Mn^{2+} , red/white light can be generated with higher

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color stability. Energy transfers from Ce^{3+} to Tb^{3+} and from Ce^{3+} to Mn²⁺ are investigated according to the Inokuti– Hirayama theoretical model.

2. EXPERIMENTAL SECTION

2.1. Sample Preparation. The $Ca_{1-x-z}Sc_{1-y}AlSiO_6(CSAS)$: xCe^{3+} ,yTb³⁺,zMn²⁺ phosphors were synthesized by a high-temperature solid-state reaction. The constituent oxides or carbonates $CaCO₃$ (99.9%), Sc_2O_3 (99.9%), SiO_2 (99.9%), Al_2O_3 (99.9%), CeO_2 (99.99%), Tb_4O_7 (99.99%), and MnCO₃ (99.99%) were employed as raw materials, which were mixed homogeneously by an agate mortar for 30 min, placed in a crucible with a lid, and then sintered in a tubular furnace at 1400 °C for 4 h in a reductive atmosphere (10% H_2) $+$ 90% N₂ mixed flowing gas).

2.2. Measurements and Characterization. The structure of sintered samples was identified by powder X-ray diffraction (XRD) analysis (Bruker AXS D8), with graphite-monochromatized Cu K α radiation ($\lambda = 0.15405$ nm) operating at 40 kV and 40 mA. Crystal structure refinement employed the Rietveld method, as implemented in the General Structure Analysis System (GSAS) program.²⁹ The measurements of photoluminescence (PL) and photolumin[es](#page-5-0)cence excitation (PLE) spectra were performed using a Hitachi F4500 spectrometer equipped with a 150 W xenon lamp under a working voltage of 700 V. The excitation and emission slits were both set at 2.5 nm. The luminescence decay curve was obtained from a Lecroy Wave Runner 6100 digital oscilloscope (1 GHz) using a tunable laser (pulse width = 4 ns; gate = 50 ns) as the excitation source (Continuum Sunlite OPO). The quantum efficiency yields were analyzed with a PL quantum-efficiency measurement system (C9920-02, Hamamatsu Photonics, Shizuoka, Japan) by a 150 W xenon lamp. All of the measurements were performed at room temperature.

3. RESULTS AND DISCUSSION

3.1. XRD Refinement. The experimental (crosses), calculated (solid line), and difference (bottom) XRD profiles for the Rietveld refinement of CSAS:0.02Ce³⁺ are shown in Figure 1. The starting structural model was constructed with crystallographic data previously reported for CSAS (JCPDS 77- 0465).³⁰ All of the observed XRD peaks are obtained with goodn[es](#page-5-0)s-of-fit parameters $R_{wp} = 6.11\%$ and $\chi^2 = 4.293$. CSAS has space group $C2/c$ with unit cell parameters $a = 9.877 \text{ Å}$, $b =$ 9.003 Å, and $c = 5.446$ Å. The crystallographic data and selected

Figure 1. Experimental (crosses), calculated (solid line), and difference (bottom) XRD profiles for the Rietveld refinement of CSAS:0.02Ce³⁺. The rather unusual background in the 10−20° range is an artifact going back to the setup of the evacuated flat sample holder.

bond lengths are summarized in Table 1. The average bond distances for Ca−O and Sc−O for the CSAS compounds in the

Table 1. Crystallographic Data and Selected Bond Lengths

crystallographic data of CSAS		seleted bond lengths (A)	
radiation type/Å	1.54056	$Ca-O1$	2.44955(8)
2θ range/deg	$10 - 100$	$Ca - O2$	2.38465(10)
T/K	295	$Ca - O3$	2.54429(8)
symmetry	monoclinic	$Ca - O3$	2.67847(8)
space group	C2/c	$Sc-O1$	2.18422(7)
a/Å	9.877	$Sc-O1$	2.10339(9)
b/Å	9.003	$Sc - O2$	2.02073(6)
$c/\text{\AA}$	5.446	$Si-O1$	1.68834(9)
α /deg	90	$Si-O2$	1.66463(6)
β /deg	106	$Si-O3$	1.70776(5)
γ /deg	90	$Si-O3$	1.72112(6)
volume/Å	465.91	$Al-O1$	1.68834(3)
$R_p/\%$	4.51	$Al-O2$	1.66463(6)
$R_{\rm wp}/\%$	6.11	$Al - O3$	1.70776(5)
χ^2	4.293	$Al-O3$	1.72112(6)

present work are 2.5142 and 2.1028 Å, respectively. These values are similar to the typical values of the Ca−O and Sc−O bonds $[Ca-O = 2.390(4)$ Å and Sc−O = 2.099(6) Å in the $Ca₃Sc₂Si₃O₁₂$ system. Figure 1, inset, shows the coordination environments of CASC compounds, in which two types of independent cation sites are found, namely, an 8-foldcoordinated Ca^{2+} site and a 6-fold-coordinated Sc^{2+} site. On the basis of the effective ionic radii (r) of cations with different coordination numbers (CNs) as reported by Shannon,^{[31](#page-5-0)} it is demonstrated that Ce^{3+} is expected to occupy a Ca^{2+} site because the ionic radius of $Ce^{3+}(1.14 \text{ Å})$ is close to that of Ca^{2+} (1.12 Å) . As for Tb³⁺ $(0.92 \text{ Å}$ for CN = 6, 1.04 Å for CN = 8), it is uncertain where the Tb^{3+} ions exactly occupy. However, accounting for ion valence, we presume that Tb^{3+} may be favorable to occupying Sc^{3+} . When Mn^{2+} is incorporated into the crystal structure of CSAS, we propose that Mn^{2+} may substitute both Ca^{2+} and Sc^{3+} sites, because the Mn^{2+} ionic radius ($r = 0.96$ Å for CN = 8; $r = 0.83$ Å for CN = 6) is not only close to that of Ca^{2+} ($r = 1.12$ Å for CN = 8) but also similar to that of Sc^{3+} ($r = 0.75$ Å for CN = 6). Mn^{2+} substitution for Ca^{2+} and Sc^{3+} is actually observed in the PL spectra of the samples presented in section 3.3.

3.2. Luminescence Properties [and Energ](#page-3-0)y Transfer in $CSAS:Ce³⁺, Tb³⁺$. Figure 2 shows the PL and PLE spectra in $CSAS: 0.02Ce^{3+}$ (a[\)](#page-2-0), $CSAS: 0.1Tb^{3+}$ (b) and $CSS:0.02Ce^{3+},0.1Tb^{3+}$ (c). It can be seen that the excitation spectrum of $CSAS:Ce^{3+}$ (monitored at 380 nm) consists of three components, having peaks at 245, 296, and 340 nm (the strongest), respectively, which correspond to the electronic transitions from the ground state to the different crystal-fieldsplitting bands of excited 5d states of $Ce³⁺$, while the emission spectrum appears as an intense violet light with a peak at 380 nm, which originated from the 5d \rightarrow 4f transition of Ce³⁺. The PLE spectrum of Tb^{3+} consists of several lines in the region from 300 to 500 nm, which correspond to the absorption f−f transition of the Tb^{3+} ion. The Tb^{3+} emission lines are located at 485, 542, 580, and 620 nm, which are assigned to the ${}^{5}D_4 \rightarrow {}^{7}F^-$ = (*I* = 6, 5, 4, 3) multiplet transitions, respectively ${}^{7}F_{1}$ = (J = 6, 5, 4, 3) multiplet transitions, respectively. Compared to the PL spectrum of $CSAS:Ce^{3+}$ (Figure 2a), that of CSAS:Tb³⁺ shows very weak emission upon [U](#page-2-0)V-light excitation due to forbidden f–f absorption transitions of Tb³⁺

Figure 2. PL and PLE spectra in CSAS: $0.02Ce^{3+}$ (a), CSAS: $0.1Tb^{3+}$ (b), and CSS:0.02Ce³⁺,0.1Tb³⁺ (c).

in UV. It is clearly exhibited that there is a significant spectral overlap between the Ce^{3+} PL and Tb^{3+} PLE spectra, indicating the possibility of energy transfer from Ce^{3+} to Tb³⁺ in CSAS. Figure 2c illustrates the PLE and PL spectra of CSAS:0.02- Ce^{3+} ,0.1Tb³⁺. It is observed that the PLE spectrum monitoring the 542 nm emission of Tb^{3+} is similar to that monitoring the violet emission of Ce^{3+} , demonstrating the existence of energy transfer from Ce^{3+} to Tb^{3+} , while the emission intensity of Tb^{3+} is considerably enhanced compared to the Ce^{3+} emission because of energy transfer from Ce^{3+} to Tb³⁺. Figure 3 shows a

Figure 3. Series of emission spectra for CSAS:0.02 Ce^{3+} , yTb^{3+} ($y = 0$, 0.02, 0.04, 0.06, 0.08, 0.10, 0.12) under UV excitation ($\lambda_{\rm ex}$ = 330 nm).

series of emission spectra for CSAS:0.02Ce³⁺, y Tb³⁺ ($y = 0$, 0.02, 0.04, 0.06, 0.08, 0.10, 0.12) under UV excitation ($\lambda_{\rm ex} = 330$ nm). With increasing Tb^{3+} concentration, the emission intensities of Tb^{3+} increase followed by decreases of the Ce^{3+} emission intensities, reflecting the result of energy transfer from Ce^{3+} to Tb^{3+} .

To further validate the process of energy transfer, the fluorescence lifetimes τ for Ce³⁺ with different Tb³⁺ concentrations are measured and presented in Figure 4. The values of the lifetimes are obtained by integrating the decay curves, of which the initial intensities are normalized. With increasing Tb^{3+} concentration, the fluorescence decreases and tends to be a nonexponential function with increasing Th^{3+}

Figure 4. Fluorescence lifetimes τ for Ce³⁺ with different Tb³⁺ concentrations. Inset: Calculated energy-transfer efficiency with different doping Tb^{3+} contents.

concentrations, reflecting the characteristics of energy transfer between Ce³⁺ and Tb³⁺.^{[32](#page-5-0)} The energy-transfer efficiency $\eta_{\text{Ce-Tb}}$ can be calculated using

$$
\eta_{\text{Ce-Tb}} = 1 - \tau/\tau_0 \tag{1}
$$

where τ_0 is the lifetimes for Ce³⁺ in the absence of Tb³⁺. The calculated energy-transfer efficiency is shown in Figure 4, inset. The efficiency $\eta_{\text{Ce-Tb}}$ increases with increasing x and reaches 35% at $\nu = 0.12$.

The decays in Figure 4 change from exponential to nonexponential patterns with increasing x , reflecting the effect of energy transfer. If the donor and acceptor ions are uniformly distributed in the host, the migration process is negligible compared to energy transfer between donors and acceptors. The normalized intensity of the donor fluorescence can be written as

$$
I_{D}(t) = I_{D0}(t) f(t)
$$
 (2)

where $I_{\text{D}0}(t)$ is the decay function of donors in the absence of acceptors and the function $f(t)$ characterizes the loss of excited donors due to one-way energy transfer to the acceptors. According to the Inokuti–Hirayama formula,^{[32](#page-5-0)} we have

$$
f(t) = \exp\left[-\frac{4}{3}\pi\Gamma\left(1 - \frac{3}{m}\right) n_A \alpha^{3/m} t^{3/m}\right]
$$
\n(3)

where α is a rate constant for energy transfer, $m = 6$, 8, and 10 are the coefficients for dipole−dipole, dipole−quadrupole, and quadrupole−quadrupole interactions, respectively, and n_A is the number of acceptor ions per unit volume. From eqs 2 and 3, $log{[ln[I_{D0}(t)/I_D(t)]]}$ acts as a linear function of $log(t)$ with a slope of 3/m. In order to well understand the Ce−Tb energytransfer process, we plot $\log{\{\ln[I_{\text{D0}}(t)/I_{\text{D}}(t)]\}}$ versus $\log(t)$ for various samples, as shown in Figure 5. The values of S estimated from the slope were found to [be](#page-3-0) 5.87, 5.94, and 6.05 for CSAS:0.02Ce³⁺,yTb³⁺ samples with $n = 0.04$, 0.06, and 0.08, respectively. The values are nearly coincident with the conventional value of $m = 6$, indicating that the dominant interaction mechanism for $CSAS:Ce^{3+},Tb^{3+}$ is based on the dipole−dipole interaction.

For the dipole−dipole interaction mechanism, the critical distance (R_c) for energy transfer from Ce^{3+} to Tb^{3+} can be obtained by the spectral overlap method:^{[33](#page-5-0)}

Figure 5. $\log{\ln[I_{\text{D0}}(t)/I_{\text{D}}(t)]}$ vs $\log(t)$ for various Tb³⁺ contents.

$$
R_c^6 = 3.024 \times 10^{12} f_q \int \frac{F_S(E) F_A(E) dE}{E^4}
$$
 (4)

where f_q is the oscillator strength of the involved absorption transition of the acceptor (Tb^{3+}) , (34) is the wavelength position of the sensitizer's emission, E is the energy involved in the transfer (in eV), and $\int F_S(E) F_A(E) dE/E^4$ represents the spectral overlap between the normalized shapes of the Ce^{3+} emission $F_S(E)$ and the Tb³⁺ excitation $F_A(E)$, and in our case, it is calculated to be about 0.0114 eV^{-5} . Using the above equation with $f_q = 10^{-6}$, the critical distance R_c was estimated to be 5.8 Å.

3.3. Luminescence Properties and Energy Transfer in **CSAS:Ce³⁺,Mn²⁺.** The PL and PLE spectra of the Ce³⁺ and Mn^{2+} singly doped CSAS phosphors are shown in Figure 6a,b.

Figure 6. PL and PLE spectra in CSAS: $0.02Ce^{3+}$ (a), CSAS: $0.04Mn^{2+}$ (b), and CSS:0.02Ce³⁺,0.2Mn²⁺ (c).

The PL spectrum of Mn^{2+} singly doped CSAS exhibits two emission bands: one is a yellow emission band around 590 nm [named $Mn^{2+}(I)$], and the other one is a red emission band around 670 nm [named $Mn^{2+}(II)$]. The shape of the PLE spectrum monitored at 590 nm is remarkably different from that monitored at 670 nm. Therefore, we infer that there exist two types of Mn^{2+} luminescent centers in the CSAS system. As we know, the crystal structure of CSAS provides two different sites for the cautions in it, i.e., a 8-fold-coordinated Ca^{2+} site and a 6-fold-coordinated Sc^{2+} site. Thus, the observed two emission bands of Mn^{2+} $[Mn^{2+}(I)]$ and $Mn^{2+}(II)]$ indicate that Mn^{2+} ions can occupy both Ca^{2+} and Sc^{3+} sites. Considering that the average distance for Ca−O (2.5142 Å) is significantly longer than that for Sc−O (2.1028 Å) ,³¹ it is therefore speculated that the crystal-field effects for the Ca^{2+} site are weaker than those for the Sc^{3+} site. For this reason, we believe that the band at 590 nm is assigned to $Mn^{2+}(I)$ occupying Ca^{2+} with a weak crystal field and the other one at 670 nm corresponds to $Mn^{2+}(II)$ occupying Sc^{3+} with a strong crystal field. Similar observations were also reported by Liu et al. for Ce^{3+} -doped $Ca_3Sc_2Si_3O_{12}$.¹⁹ Figure 6c illustrates the PLE and PL spectra of CSAS: $0.02Ce^{2+}$ $0.02Ce^{2+}$ $0.02Ce^{2+}$, $0.2Mn^{2+}$. It is found that the PLE spectra monitoring the yellow emission of $Mn^{2+}(I)$ and the red emission of $Mn^{2+}(II)$ are all similar to those monitoring the blue emission of Ce^{3+} , demonstrating the existence of energy transfer from Ce^{3+} to Mn^{2+} in CASC systems. Meanwhile, the Mn^{2+} emission intensities are enhanced greatly compared to $\rm Mn^{2+}$ singly doped CASC. These results give strong evidence of the effective Ce3+−Mn2+ energy transfer. The occurrence of energy transfer can be clearly understood as noticing the spectral overlap between the Ce^{3+} emission band in $CSAS: 0.02Ce^{3+}$ and the Mn^{2+} excitation band in $CSAS: 0.04Mn^{2+}$. Figure 7 shows the normalized emission

Figure 7. Normalized emission spectra for $CSAS: 0.02Ce³⁺, zMn²⁺$ phosphors with increasing z from 0 to 0.20 under UV excitation $(\lambda_{\rm ex} = 330 \text{ nm}).$

spectra for CSAS:0.02Ce³⁺, z Mn²⁺ phosphors with increasing z from 0 to 0.20, which were measured at an excitation wavelength of 330 nm. With increasing concentration of Mn^{2+} , the emission intensity of Mn^{2+} ions increases systematically due to $Ce^{3+}-Mn^{2+}$ energy transfer. In addition, it is noticeable that the relative emission intensity of the $Mn^{2+}(I)$ ions decreases, which might be due to concentration quenching.

The decay curves of Ce^{3+} fluorescence in CSAS:0.02- $Ce^{3+}zMn^{2+}$ ($z = 0, 0.04, 0.08, 0.12, 0.16,$ and 0.2) are also measured and shown in Figure 8. The reduction of the lifetimes for Ce^{3+} with increasing Mn^{2+} Mn^{2+} Mn^{2+} concentrations is observed. These results support the efficient energy transfer from $Ce³⁺$ to Mn^{2+} . The energy-transfer efficiency can be obtained using eq 1, as shown in Figure 8, inset. It can be seen that the values of [th](#page-2-0)e energy-transfer e[ffi](#page-4-0)ciency $\eta_{\text{Ce-Mn}}$ gradually increase and reach 54% for Mn^{2+} concentrations at $z = 0.2$, further implying that the energy of the red emission of Mn^{2+} is derived from $Ce³⁺$. Using eqs 2 and 3, the value of S was also estimated from the slope and fou[nd](#page-2-0) to be 6.11, 5.91, and 6.14 for

Figure 8. Decay curves of Ce^{3+} fluorescence in CSAS:0.02 Ce^{3+} , zMn^{2+} $(z = 0, 0.04, 0.08, 0.12, 0.16,$ and 0.2) Inset: Energy-transfer efficiency $(\eta_{\text{Ce-Mn}})$ with different doping Mn²⁺ contents.

CSAS:0.02Ce³⁺,zMn²⁺ samples with $z = 0.04$, 0.08, and 0.12, respectively, as shown in Figure 9. These values are nearly coincident with the conventional value of $m = 6$, meaning that the nature of multipolar interaction for energy transfer between the donor and acceptor is also mainly governed by dipole− dipole interaction.

3.4. Quantum Yields (QYs) and Chromaticity of $CSAS:Ce^{3+}$, Tb^{3+} , Mn^{2+} . XRD patterns of CSAS:- Ce^{3+} ,Tb³⁺,Mn²⁺ with various Tb³⁺ and Mn²⁺ concentrations are shown in Figure 10. All of the observed peaks can be

indexed to the standard data of CSAS with JCPDS 77-0465. No obvious impurity phase was detected when Th^{3+} and Mn^{2+} were doped into the host lattice.

The absolute QY is an important parameter to be considered for practical LED application. So, the absolute QYs of the obtained phosphors were also measured. Upon excitation at 340 nm, for CSAS: Ce^{3+} , yTb^{3+} ($y = 0$, 0.02, 0.04, 0.06, 0.08, 0.10, and 0.12) phosphors, the absolute QYs were determined to be 96.8%, 93.3%, 91.6%, 87.1%, 81.1%, 80.5%, and 79.5%,

Figure 10. XRD patterns of CSAS: Ce^{3+} ,Tb³⁺,Mn²⁺ with varying Tb³⁺ and Mn^{2+} concentrations.

respectively. For the CSAS:0.02Ce³⁺,zMn²⁺ ($z = 0$, 0.04, 0.08, 0.12, 0.16, and 0.2) series of samples, the absolute QYs were determined to be 97.1%, 87.6%, 80.4%, 73.4%, 67.3%, and 65.5%, respectively. The high QY of these phosphors indicates that CSAS is a quite suitable matrix for rare-earth ion doping. The CIE chromaticity diagrams of the emitting phosphors $CSAS:Ce^{3+}$, yTb^{3+} , zMn^{2+} with different compositional concentrations $(y \text{ and } z)$ are displayed in Figure 11. The color tone

Figure 11. CIE chromaticity diagram and a series of digital photographs of the selected $CSAS:Ce^{3+}$, yTb^{3+} , zMn^{2+} phosphors under 365 nm UV-lamp excitation.

can be tuned from blue (0.17 and 0.03) to white (0.33 and 0.34) by adjusting the concentration of Tb^{3+} and from blue $(0.17 \text{ and } 0.03)$ to red $(0.44 \text{ and } 0.24)$ by varying the Mn²⁺ content, respectively. The inset in Figure 11 also shows a series of digital photographs of the selected $CSAS:Ce^{3+}$, yTb^{3+} , zMn^{2+} phosphors upon 365 nm UV-lamp excitation. In particular, it is found that $CSAS: 0.04Ce³⁺, 0.08Tb³⁺, 0.04Mn²⁺$ shows white light, suggesting that it can be used as a potential whiteemitting candidate for UV LEDs.

4. CONCLUSION

In summary, we have synthesized a series of novel emissiontunable $CSAS:Ce^{3+}$, yTb^{3+} , zMn^{2+} phosphors by a solid-state reaction. The obtained phosphor exhibits four emission colors:

a blue band of 380 nm, a green band of 542 nm, a yellow band of 574 nm, and a red band of 670 nm. Mn^{2+} may substitute either for Ca^{2+} to generate a yellow emission band (574 nm) or for Sc^{3+} to generate a red emission band (670 nm). The energy transfer from Ce^{3+} to Tb^{3+} and from Ce^{3+} to Mn^{2+} in a CaScAlSiO6 host matrix was confirmed via a dipole−dipole mechanism by the luminescence spectra and fluorescence decay dynamics based on the Inokuti−Hirayama theoretical model. We have demonstrated that the varied emitted color from blue to green or red and eventually to white can be achieved by proper tuning of the relative ratio of Tb^{3+} and Mn^{2+} . All of these results indicate that $CSAS:Ce^{3+}, Tb^{3+}, Mn^{2+}$ is a promising single-composition phosphor for application involving white LEDs.

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Notes

The authors declare no competing financial interest.

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